



Capsule Thyristor

Line Thyristor

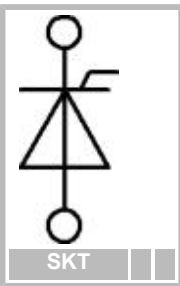
SKT 2400

Features

- Hermetic metal case with ceramic insulator
- Capsule package for double sided cooling
- Shallow design with single sided cooling
- Off-state and reverse voltages up to 1800 V
- Amplifying gate

Typical Applications

- DC motor control
(e. g. for machine tools)
- Controlled rectifiers
(e. g. for battery charging)
- AC controllers
(e. g. for temperature control)
- Soft starters for AC motors
- Recommended snubber network
e. g. for $V_{RMS} \leq 400$ V:
 $R = 33 \cdot 32$ W, $C = 1 \cdot F$



V_{RSM}	V_{RRM}, V_{DRM}	$I_{TRMS} = 5700$ A (maximum value for continuous operation)
V	V	$I_{TAV} = 2400$ A (sin. 180; DSC; $T_c = 76$ °C)
1300	1200	SKT 2400/12E
1500	1400	SKT 2400/14E
1700	1600	SKT 2400/16E
1900	1800	SKT 2400/18E

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; $T_c = 100$ (85) °C	1520 (2100)	A
I_D	2 x N4/250; $T_a = 45$ °C; B2 / B6	2650 / 3700	A
I_{RMS}	2 x N4/250; $T_a = 45$ °C; W1C	3000	A
I_{TSM}	$T_{vj} = 25$ °C; 10 ms	55000	A
	$T_{vj} = 125$ °C; 10 ms	47000	A
i^2t	$T_{vj} = 25$ °C; 8,3 ... 10 ms	15125000	A ² s
	$T_{vj} = 125$ °C; 8,3 ... 10 ms	11000000	A ² s
V_T	$T_{vj} = 25$ °C; $I_T = 3000$ A	max. 1,37	V
$V_{T(TO)}$	$T_{vj} = 125$ °C	max. 0,88	V
r_T	$T_{vj} = 125$ °C	max. 0,164	m•
$I_{DD}; I_{RD}$	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 100	mA
t_{gd}	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/ μ s	1	μ s
t_{gr}	$V_D = 0,67 \cdot V_{DRM}$	2	μ s
$(di/dt)_{cr}$	$T_{vj} = 125$ °C	max. 150	A/ μ s
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C	max. 1000	V/ μ s
t_q	$T_{vj} = 125$ °C	200 ... 300	μ s
I_H	$T_{vj} = 25$ °C; typ. / max.	500 / 1000	mA
I_L	$T_{vj} = 25$ °C; typ. / max.	2000 / 5000	mA
V_{GT}	$T_{vj} = 25$ °C; d.c.	min. 3	V
I_{GT}	$T_{vj} = 25$ °C; d.c.	min. 300	mA
V_{GD}	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
I_{GD}	$T_{vj} = 125$ °C; d.c.	max. 10	mA
$R_{th(j-c)}$	cont.; DSC	0,0105	K/W
$R_{th(j-c)}$	sin. 180; DSC / SSC	0,011 / 0,024	K/W
$R_{th(j-c)}$	rec. 120; DSC / SSC	0,0118 / 0,025	K/W
$R_{th(c-s)}$	DSC / SSC	0,002 / 0,004	K/W
T_{vj}		- 40 ... + 125	°C
T_{stg}		- 40 ... + 130	°C
V_{isol}		-	V~
F	mounting force	37 ... 47	kN
a			m/s ²
m	approx.	1000	g
Case		B 20	

Diagrams

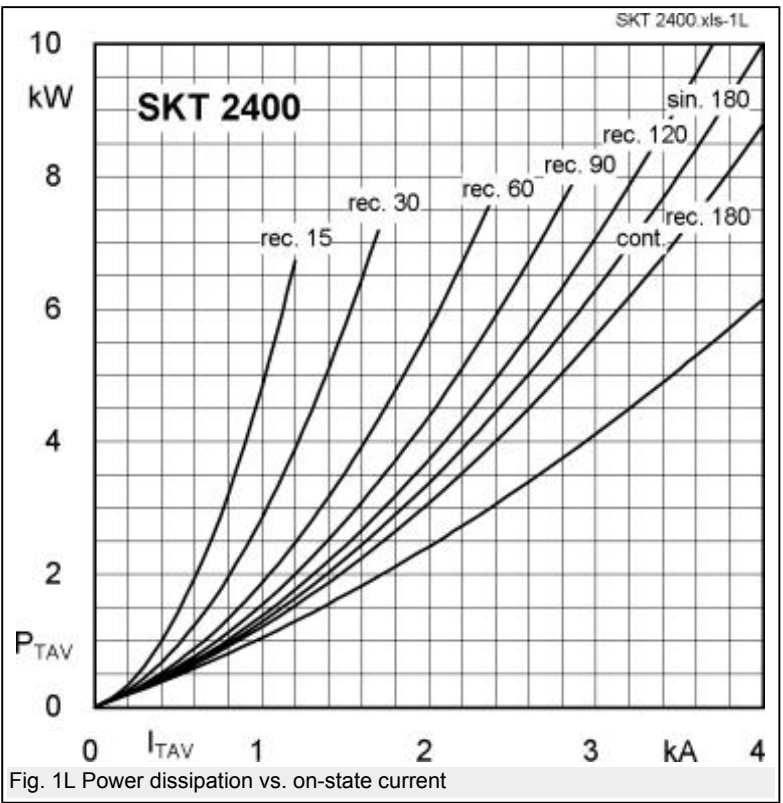


Fig. 1L Power dissipation vs. on-state current

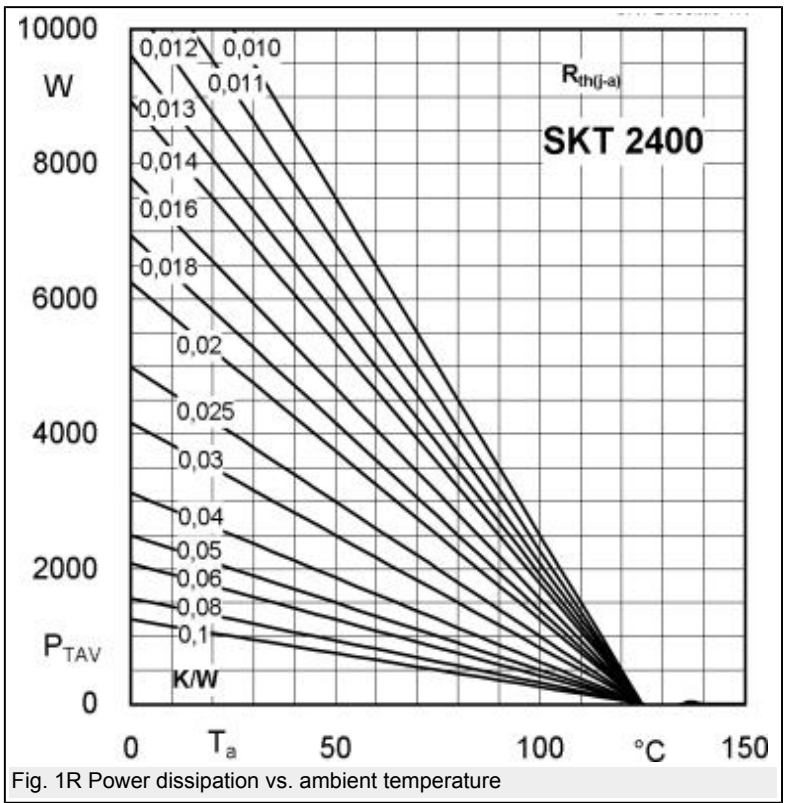


Fig. 1R Power dissipation vs. ambient temperature

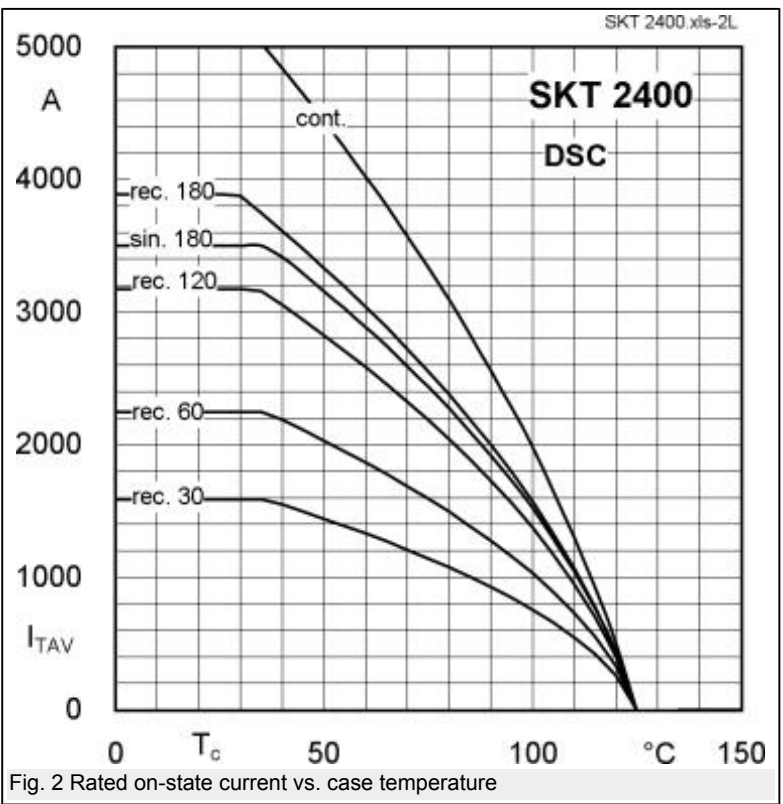


Fig. 2 Rated on-state current vs. case temperature

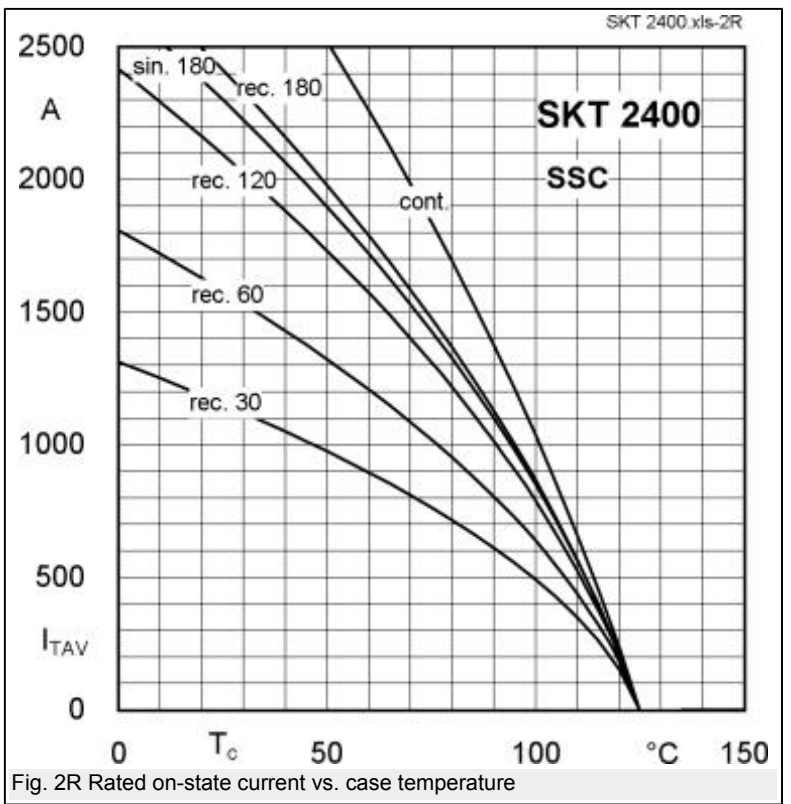


Fig. 2R Rated on-state current vs. case temperature

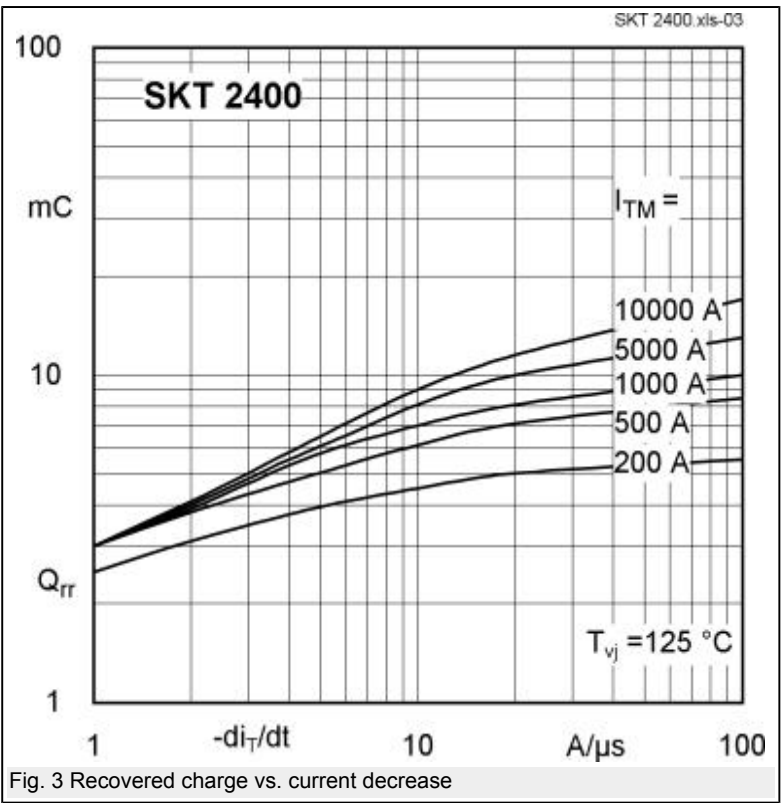


Fig. 3 Recovered charge vs. current decrease

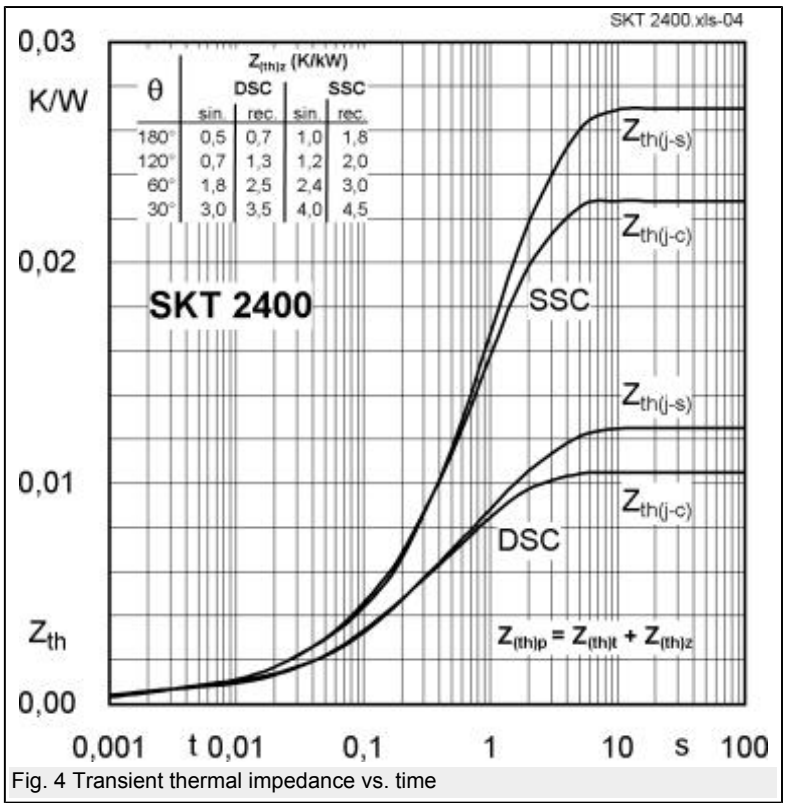


Fig. 4 Transient thermal impedance vs. time

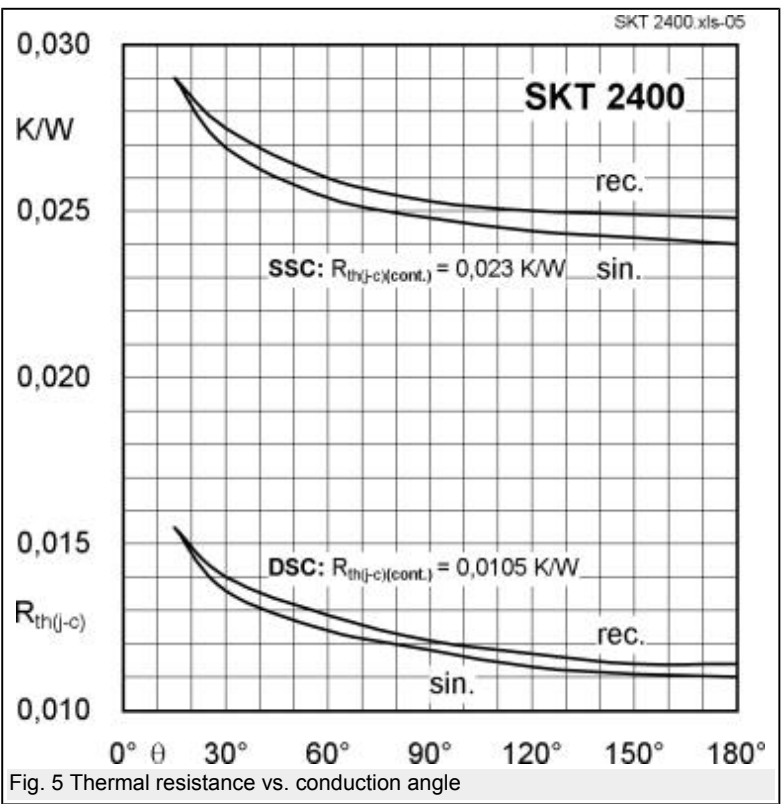


Fig. 5 Thermal resistance vs. conduction angle

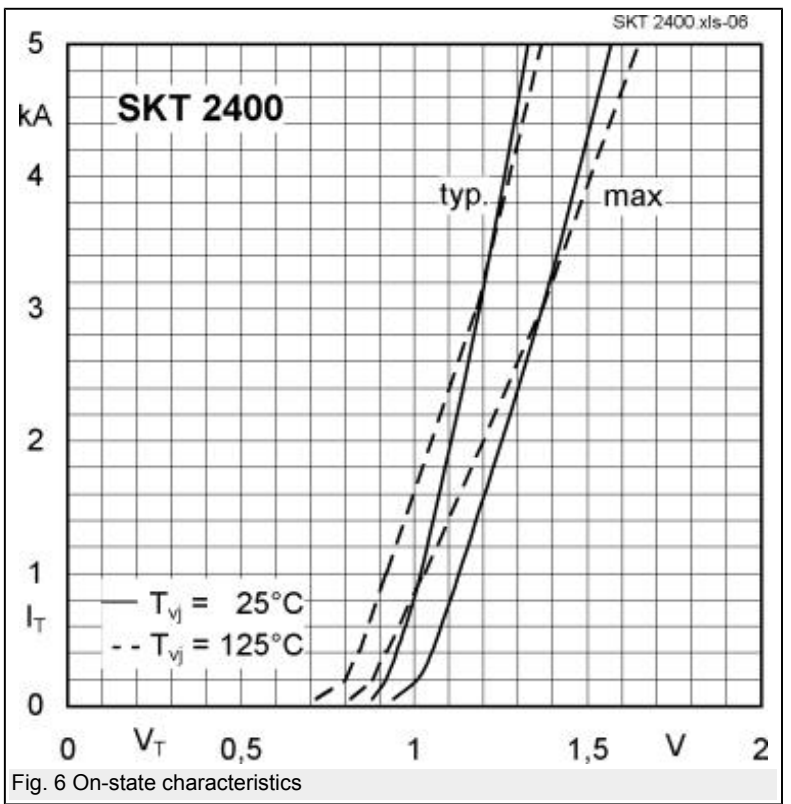
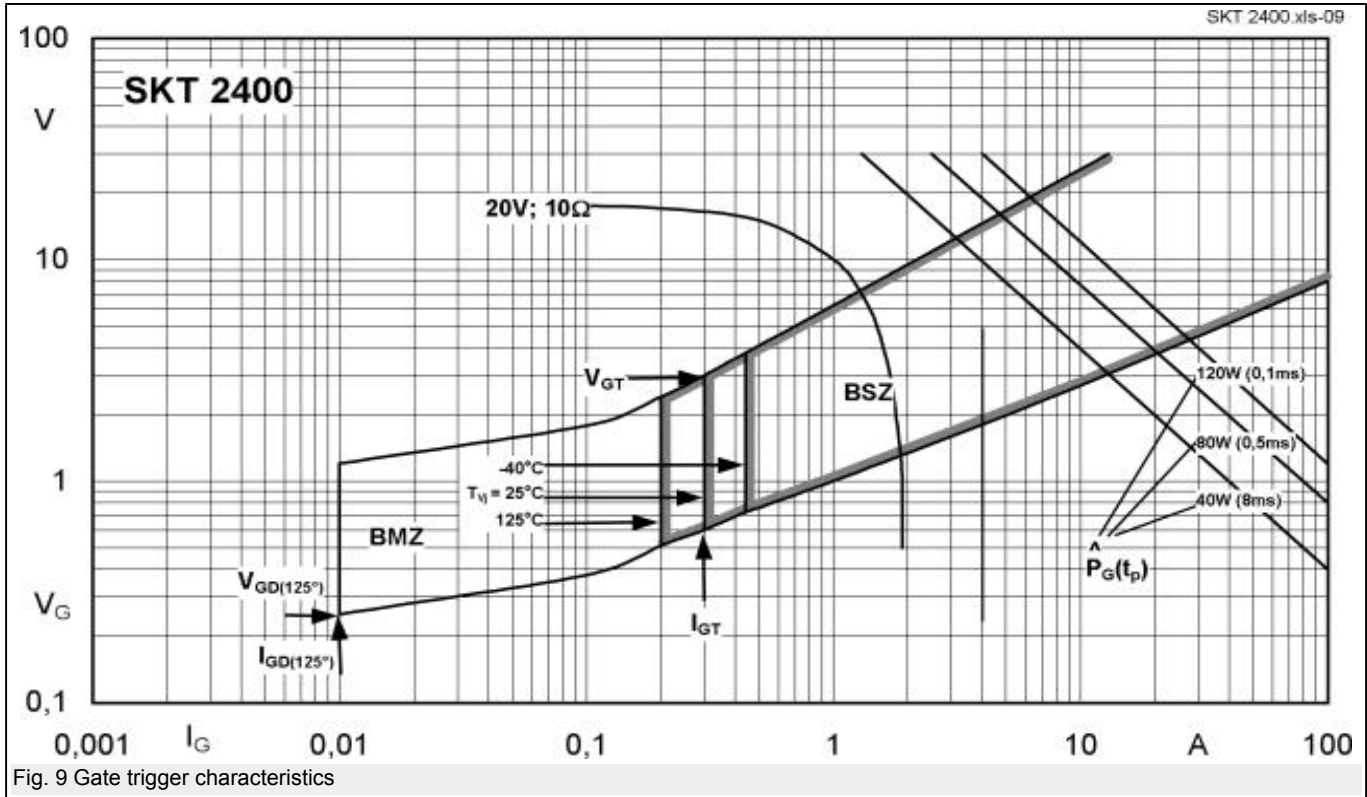
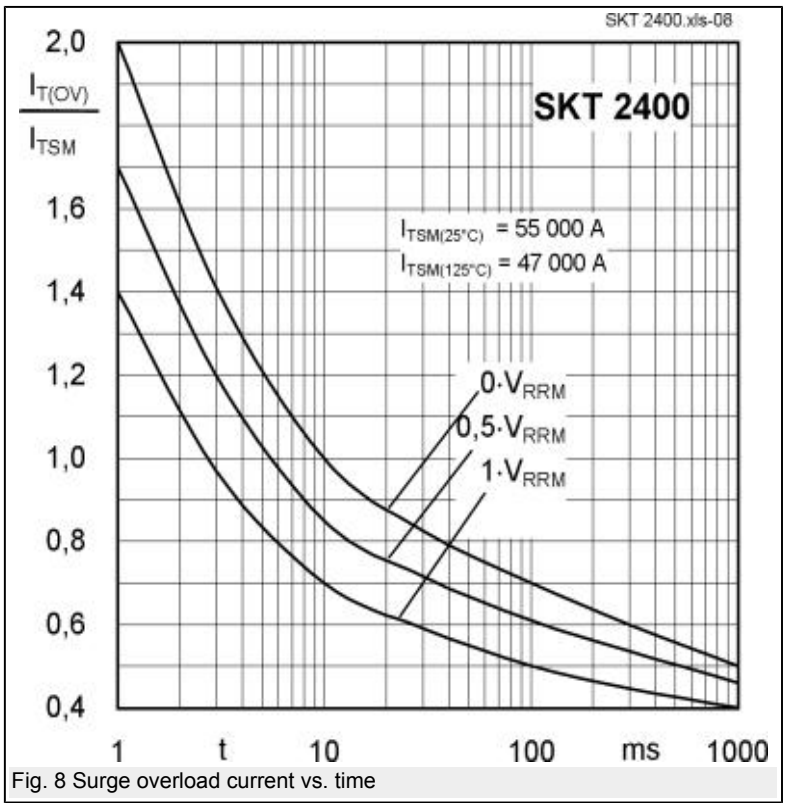
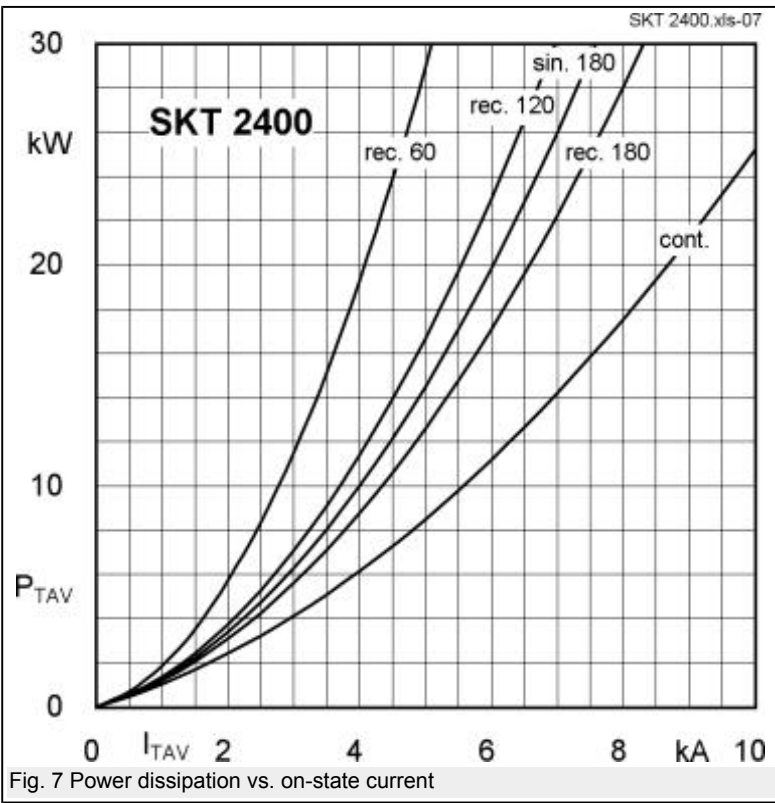
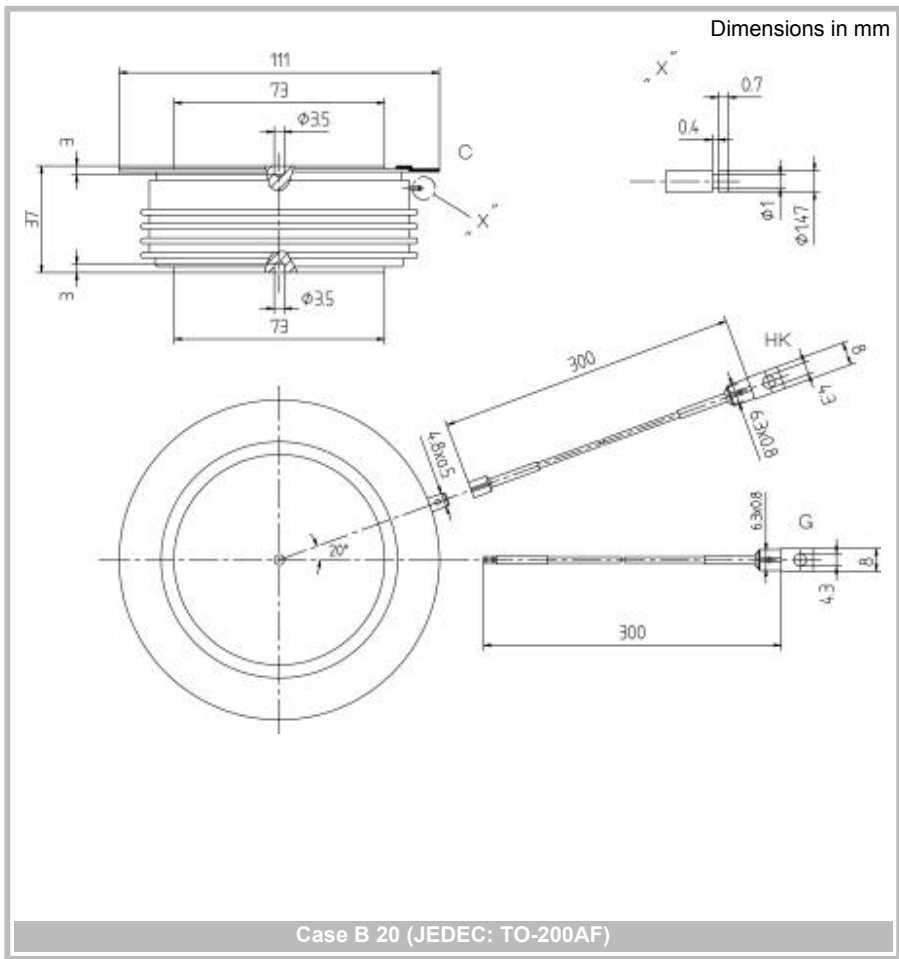


Fig. 6 On-state characteristics



Cases / Circuits



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